Designed to Reduce Reflection Noise
- Repetitive Peak Forward Current 300 mA
- 8-Bit Array Structure Suited for Bus-Oriented Systems

description

This Schottky barrier diode bus-termination array is designed to reduce reflection noise on memory bus lines. This device consists of an 8-bit high-speed Schottky diode array suitable for a clamp to GND.

The SN74F1056 is characterized for operation from 0°C to 70°C.

schematic diagrams

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

<table>
<thead>
<tr>
<th>PARAMETER</th>
<th>TEST CONDITIONS</th>
<th>MIN</th>
<th>TYP ‡</th>
<th>MAX</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>VR</td>
<td>Steady-state reverse voltage, VR = 7 V</td>
<td>7 V</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>IF</td>
<td>Continuous forward current, IF: Any D terminal from GND</td>
<td>50 mA</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td>Total through all GND terminals</td>
<td>170 mA</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>IRFM</td>
<td>Repetitive peak forward current, IRFM (see Note 1): Any D terminal from GND</td>
<td>300 mA</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td>Total through all GND terminals</td>
<td>1.2 A</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>PD</td>
<td>Continuous total power dissipation at (or below) 25°C free-air temperature</td>
<td>500 mW</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Tstg</td>
<td>Operating free-air temperature range</td>
<td>0°C to 70°C</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td>Storage temperature range, Tstg</td>
<td>–65°C to 150°C</td>
<td></td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: These values apply for tw ≤ 100 µs, duty cycle ≤ 20%.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

single-diode operation (see Note 2)

<table>
<thead>
<tr>
<th>PARAMETER</th>
<th>TEST CONDITIONS</th>
<th>MIN</th>
<th>TYP ‡</th>
<th>MAX</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>IR</td>
<td>Static reverse current</td>
<td>VR = 7 V</td>
<td>2 µA</td>
<td></td>
<td></td>
</tr>
<tr>
<td>VF</td>
<td>Static forward voltage</td>
<td>IF = 18 mA</td>
<td>0.8 V</td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>IF = 50 mA</td>
<td>1 V</td>
<td></td>
<td></td>
</tr>
<tr>
<td>VFm</td>
<td>Peak forward voltage</td>
<td>IF = 200 mA</td>
<td>1.23 V</td>
<td></td>
<td></td>
</tr>
<tr>
<td>CT</td>
<td>Total capacitance</td>
<td>VR = 0, f = 1 MHz</td>
<td>3 pF</td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>VR = 2 V, f = 1 MHz</td>
<td>2.5 pF</td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

‡ All typical values are at TA = 25°C.

NOTE 2: Test conditions and limits apply separately to each of the diodes. The diodes not under test are open-circuited during the measurement of these characteristics.

multiple-diode operation

<table>
<thead>
<tr>
<th>PARAMETER</th>
<th>TEST CONDITIONS</th>
<th>MIN</th>
<th>TYP ‡</th>
<th>MAX</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>IX</td>
<td>Internal crosstalk current</td>
<td>Total GND current = 1.2 A, See Note 3</td>
<td>10 µA</td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

‡ All typical values are at TA = 25°C.

NOTE 3: IX is measured under the following conditions with one diode static, all others switching:
- Switching diodes: tw = 100 µs, duty cycle = 20%
- Static diode: VR = 5 V
- The static diode input current is the internal crosstalk current IX.

switching characteristics, TA = 25°C

<table>
<thead>
<tr>
<th>PARAMETER</th>
<th>TEST CONDITIONS</th>
<th>MIN</th>
<th>TYP</th>
<th>MAX</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>ttr</td>
<td>Reverse recovery time</td>
<td>IF = 10 mA, IRM(REC) = 10 mA, IR(REC) = 1 mA, RL = 100 Ω</td>
<td>5 ns</td>
<td></td>
<td>7 ns</td>
</tr>
</tbody>
</table>

undershoot characteristics

<table>
<thead>
<tr>
<th>PARAMETER</th>
<th>TEST CONDITIONS</th>
<th>MIN</th>
<th>TYP</th>
<th>MAX</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>VUS</td>
<td>Undershoot voltage</td>
<td>IF = 2 ns, tw = 50 ns, VIL = 5 V, VIL = 0, ZS = 25 Ω, ZO = 50 Ω, L = 36-inch coax</td>
<td>0.6 V</td>
<td></td>
<td>0.7 V</td>
</tr>
</tbody>
</table>
APPLICATION INFORMATION

Large negative transients occurring at the inputs of memory devices (DRAMs, SRAMs, EPROMs, etc.) or on the CLOCK lines of many clocked devices can result in improper operation of the devices. The SN74F1056 diode termination array helps suppress negative transients caused by transmission-line reflections, crosstalk, and switching noise.

Diode terminations have several advantages when compared to resistor termination schemes. Split resistor or Thevenin equivalent termination can cause a substantial increase in power consumption. The use of a single resistor to ground to terminate a line usually results in degradation of the output high level, resulting in reduced noise immunity. Series damping resistors placed on the outputs of the driver reduce negative transients, but they also can increase propagation delays down the line, as a series resistor reduces the output drive capability of the driving device. Diode terminations have none of these drawbacks.

The operation of the diode arrays in reducing negative transients is explained in the following figures. The diode conducts current when the voltage reaches a negative value large enough for the diode to turn on. Suppression of negative transients is tracked by the current-voltage characteristic curve for that diode. A typical current versus voltage plot for the SN74F1056 is shown in Figure 1.

To illustrate how the diode arrays act to reduce negative transients at the end of a transmission line, the test setup in Figure 2(a) was evaluated. The resulting waveforms with and without the diode are shown in Figure 2(b).

The maximum effectiveness of the diode arrays in suppressing negative transients occurs when the diode arrays are placed at the end of a line and/or the end of a long stub branching off a main transmission line. The diodes also can be used to reduce the negative transients that occur due to discontinuities in the middle of a line. An example of this is a slot in a backplane that is provided for an add-on card.

![DIODE FORWARD CURRENT vs DIODE FORWARD VOLTAGE](image)

**Figure 1. Current Versus Voltage for the SN74F1056**
APPLICATION INFORMATION

Z₀ = 50 Ω
Length = 36 in.

(a) UNDERSHOOT TEST SETUP

Zₛ = 25Ω

Figure 2. Undershoot Test Setup and Oscilloscope Display

(b) OSCILLOSCOPE DISPLAY

Ch 1 = 2.000 V/div
Timebase = 5.00 ns/div
Vmarker 1 = 0.0000 V
Vmarker 2 = –600.00 mV

Offset = 2.340 V
Delay = 1.06110 µs
Delta V = –600.0 mV
### PACKAGING INFORMATION

<table>
<thead>
<tr>
<th>Orderable Device</th>
<th>Status (1)</th>
<th>Package Type</th>
<th>Package Drawing</th>
<th>PIns</th>
<th>Package Qty</th>
<th>Eco Plan (2)</th>
<th>Lead/Ball Finish</th>
<th>MSL Peak Temp</th>
<th>Op Temp (°C)</th>
<th>Device Marking (4/5)</th>
<th>Samples</th>
</tr>
</thead>
<tbody>
<tr>
<td>SN74F1056D</td>
<td>ACTIVE</td>
<td>SOIC</td>
<td>D</td>
<td>16</td>
<td>40</td>
<td>Green (RoHS &amp; no Sb/Br)</td>
<td>CU NIPDAU</td>
<td>Level-1-260C-UNLIM</td>
<td>0 to 70</td>
<td>F1056</td>
<td></td>
</tr>
<tr>
<td>SN74F1056DR</td>
<td>ACTIVE</td>
<td>SOIC</td>
<td>D</td>
<td>16</td>
<td>2500</td>
<td>Green (RoHS &amp; no Sb/Br)</td>
<td>CU NIPDAU</td>
<td>Level-1-260C-UNLIM</td>
<td>0 to 70</td>
<td>F1056</td>
<td></td>
</tr>
</tbody>
</table>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBsolete:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) **MSL, Peak Temp.** - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a ',' will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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### TAPE AND REEL INFORMATION

<table>
<thead>
<tr>
<th>Device</th>
<th>Package Type</th>
<th>Package Drawing</th>
<th>Pins</th>
<th>SPQ</th>
<th>Reel Diameter (mm)</th>
<th>Reel Width W1 (mm)</th>
<th>A0 (mm)</th>
<th>B0 (mm)</th>
<th>K0 (mm)</th>
<th>P1 (mm)</th>
<th>W (mm)</th>
<th>Pin1 Quadrant</th>
</tr>
</thead>
<tbody>
<tr>
<td>SN74F1056DR</td>
<td>SOIC</td>
<td>D</td>
<td>16</td>
<td>2500</td>
<td>330.0</td>
<td>16.4</td>
<td>6.5</td>
<td>10.3</td>
<td>2.1</td>
<td>8.0</td>
<td>16.0</td>
<td>Q1</td>
</tr>
</tbody>
</table>

*All dimensions are nominal.*

**TAPE DIMENSIONS**

- **A0**: Dimension designed to accommodate the component width
- **B0**: Dimension designed to accommodate the component length
- **K0**: Dimension designed to accommodate the component thickness
- **W**: Overall width of the carrier tape
- **P1**: Pitch between successive cavity centers

**REEL DIMENSIONS**

- **Reel Diameter**
- **Reel Width (W1)**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**

- **Sprocket Holes**
- **User Direction of Feed**

- **Pocket Quadrants**

[Image of TAPE AND REEL INFORMATION diagram]

[Image of TAPE DIMENSIONS diagram]

[Image of REEL DIMENSIONS diagram]

[Image of QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE diagram]
**TAPE AND REEL BOX DIMENSIONS**

<table>
<thead>
<tr>
<th>Device</th>
<th>Package Type</th>
<th>Package Drawing</th>
<th>Pins</th>
<th>SPQ</th>
<th>Length (mm)</th>
<th>Width (mm)</th>
<th>Height (mm)</th>
</tr>
</thead>
<tbody>
<tr>
<td>SN74F1056DR</td>
<td>SOIC</td>
<td>D</td>
<td>16</td>
<td>2500</td>
<td>333.2</td>
<td>345.9</td>
<td>28.6</td>
</tr>
</tbody>
</table>

*All dimensions are nominal*
NOTES:

A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

⚠️ Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.

⚠️ Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.

E. Reference JEDEC MS-012 variation AC.
NOTES:  
A. All linear dimensions are in millimeters.  
B. This drawing is subject to change without notice.  
C. Publication IPC-7351 is recommended for alternate designs.  
D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.  
E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.
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